RF System in Accelerator

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Introduction **RF Source Importance**

- Modern Accelerator is so called "RF accelerator", and RF is the key technology.
- Accelerator frequency is ruled by the existence of the rf source of matched frequency.
- RF system is expensive and large fraction of total cost is shared in RF source. Therefore choice of RF is very important.
- RF source is the source of failure (arcing etc.) and careful availability consideration and constant effort of maintenance are required.

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Early Accelerator and RF

Introduction(1) History of the Linac(1) **Circular Accelerator** Drift (constant velocity) -> li K-Cyclotron Ising(1924)**Lorentz Force Equation** Wiedroe's Linac Tarae $F=e \cdot E + e \cdot v \times B$ - Ion Source (1928)Acceleration Alvarez Linac (a) (1946)Pole Oscillator Vacuu Drift (constant velocity) Tank Coupling Deflector Electron has a circular orbit In the magnetic field. Acceleration Revolution time is constant if B=const. RF field is repeadedly used.

Cyclotron

Simple Application of low frequency RF

Idea of linear Accelerator

RF source is required. For efficient use, powerful RF Source was needed.

History of the Linac(1)

- Linac was developed after the World War II.
 - → Due to the Radar Technology for military purpose









RF Source Development

World War II forced to develop RF technology.

Short pulse high power microwave source.

Klystron was invented by Varian Brothers, in 1939. (a few microsecond, 10 MW 10cm microwave) Related high-power power supply (300kV,300A pulsed source)

RF Technology is the key technology for linear accelerator

Stanford Mark III Linac made the klystron Power of 3-order higher in 1950's..

History of Linac(2)

• Stanford University Electron Linac(1950-)

Linac=Very big electron microscope

R. Hofstadter studied nuclear structure by electron

scattering(1954-57) and was awarded a Nobel prize (1961).

Comparing with Dr. R. L. Moessbauer, Nobel Winner In 1961, he was called the son of Big Science. (~10⁻¹³ cm) Smooth Density Change

• 2 mile accelerator was constructed in SLAC (Stanford Linear Accelerator Center, CA, USA) (1966-)

- SLC(SLAC linear Collider) was constructed (1983-)
- Both cases, RF source (Klystron) was developed in SLAC

Phase of RF is important Linear Accelerator (Linac)

Charged particles are accelerated linearly.

High frequency electromagnetic wave (micro-Wave) is used for the acceleration.





In the linac, the wave is electromagnetic. That means it is made up of changing magnetic and <u>electric fields</u>

 Since the electron mass is light, it is easy to be accelerated up to the light velocity (velocity is constant).

ightarrow overall structures are the same





- Longest Linac is SLAC 2-mile Linac (3.2km and 20GeV)
- Second longest linac is KEK linac (500m and 8 GeV)
- Small linac was developed for medical use (2-3m and 30 MeV)
- Short pulse linac of which pulse duration of a few to 20 microsec.
 -----wavelength of 10cm (S-band), 5cm (C-band) and X-band (2.5cm)
- Long pulse linac of which pulse duration of a millisecc
 -----wavelength of 20cm class (L-band, ex., 1.3GHz)

Electron Linac



- Since the proton mass is 2000 times heavier than electron, it is hard to be accelerated up to the **light velocity** and depending on the β (=v/c), several structures are used in proton linac and each structure has a suitable frequency.
 - RFQ structures-----VHF band such as 201MHz-432MHz

25 Feet of Earth

Inrator Structu

- Alvarez structures/DTL(Drift Tube Linac)----same as RFQ

Proton Linac





DTL Structure



Element of ACS

RFQ Structure

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RF Sources suitable for accelerator

- Factors required to accelerator rf source
 - 1. Frequency range higher than 0.3 GHz, klystron is best rf source. Less than 0.3 GHz, Solid state amplifier, IOT and Tetrode are used.
 - 2. Peak power capability -related with energy gain, short linac, and cost benefit. How to minimize the discharge rate in tube and structures.
 - **3.** Average power capability related with duty cycle or repetition rate. Cw accelerator.
 - **4. Gain** relate with driver amplifier. High gain is preferable; Generally klystron is high gain such as 50 dB. IOT is around 20 dB. Power tetrode is poor gain.
 - 5. Phase stability klystron is voltage driven device and if applied voltage is stable, phase property is excellent.
 - 6. Simplicity, Availability and Long life klystron is much matured device and satisfy these requirements.

Available RF Sources – states of art now



Progress of Recent Solid State Amplifier



For CW use, solid-state amplifiers replace to Klystron. High efficiency is achievable.

In KEK, 20-30 kW cw solid-sate amplifier (1.3GHz)is more likely candidate than IOT or Klystron for cERL.



RF Technology

- 1. RF Source (Klystron)
- 2. PS/Mpdulator
- 3. Waveguide
- 4. LLRF



Klystron Structure and Mechanism

Key Component of Klystron

- Electron Gun
- RF Cavity
- Drift Tube
- RF Window
- Beam Collector
- Focusing Magnet
- Cooing System



Basic Mechanism of Klystron

- Electron is **velocity-modulated** in an input cavity.
- Then, electrons form bunch; density modulation
- Bunches are de-accelerated in an output cavity
 ---> beam energy to rf power

See: Inverse process of accelerator

Accelerator ----> rf power to beam energy

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Accelerator Laboratory, KEK Important parameter; Perveance

Definition of Perveance



It characterize the space charge force and deeply related with the bunching formation and therefore with efficiency. Simon's formula



Low perveance klystron has high efficiency but applied voltage is high.

Beam Bunching Theory

□ Basic Mechanism of Klystron(Linear theory)

- Electron is **velocity-modulated** in an input cavity.
- Then, electrons form bunch; density modulation
- For this bunching mechanism, a simple linear theory is educative. There are two approaches:
 - Ballistic theory: electron which has a modulated velocity propagate without any interaction with other electrons.
 - Space-charge wave theory: entire electrons behave like a wave which is ruled by space charge force, and automatically it contains the space charge force effect.

More Realistic Analysis (large Signal Analysis)

- For the interaction region near to output cavity, linear theory is not applicable and non linear large signal analysis are required.
- One dimensional analysis: Disc model
- 2.5 dimensional analysis: Particle in cell Analysis including magnetic interaction
- 3 dimensional analysis: MAFIA / MAGIC code

Comparison of the beam trace among two approach





More Realistic Analysis of Klystron

One dimensional disc model

- Constant diameter beam is expressed as series of disc and moving as ballistic manner.
- Space charge among discs is considered
- Cavity-beam interaction is properly considered.



2.5 dimensional PIC program

- Electron particle in 3D
- Solving under axial symmetric condition
- Space-charge and magnetic field effect are included.
- Realistic approach and fairly good agreement between simulation and test



Comment for IUAC Klystron

- IUAC needs the S-band klystron whose frequency is 2860 MHz. So far no commercial klystron coincides to the frequency.
- Due to the recent development of computer simulation, it is easy to do the special design, but quite independent design results in expensive cost.
- Miner change from existing 2856 MHz is easy and with minimum cost rise.

Klystron Handling

Klystron Window Shop









324MHz: J-Parc

S-band pule klystron: 50MW Measured performance of MBK: TH1801

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Operation Frequency:
Cathode Voltage:
Beam Current:
μperveance:
Number of Beams:
Cathode loading:
Max. RF Peak Power:
RF Pulse Duration:
Repetition Rate:
RF Average Power:
Efficiency:
Gain:
Solenoid Power:
Length:
Lifetime (goal):







Klystron Characteristics

• Child's Law- In space charge limit current, emission current is as follows. $I = P_{\mu}V^{3/2}$

where P_{μ} is perveance, and *I* is current, and *V* is applied voltage.

• Then, power is $P = I \bullet V = P_{\mu}V^{5/2}$ Power's variation $\delta P = 2.5P_{\mu}V^{3/2}\delta V = 5$

Power's variation

$$\frac{\delta P}{P} = \frac{2.5 P_{\mu} V^{3/2} \delta V}{P_{\mu} V^{5/2}} = \frac{5}{2} \frac{\delta V}{V}$$

• Klystron's Impedance $Z = \frac{V}{I} = \frac{V}{P\mu V^{3/2}} = \frac{1}{P\mu \sqrt{V}}$

Therefore, klystron's impedance varies with applied voltage.

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Phase Variation of RF from Klystron

- For linac, phase stability of RF is extreamly important because variation dirctly reduces to energy variaion DE
- Since klystron is voltage driven device and votage determine the electron velocity, rf phase strongly depends on the voltage variation.

$$\Delta \theta = \frac{2\pi L_0}{u_0} = \frac{2\pi L_0}{c \sqrt{1 - \frac{1}{(1 + \frac{eV_0}{mc^2})^2}}} \text{ and } \frac{\Delta \theta}{(\Delta V/V)} = 6 - 8 \quad (\frac{\deg/\omega}{2}V)$$

- Usual S-band tube operating at 300kV range, this phase variation Is roughly 6-8 deg./(dV/V%).
 If you want to get ∆E /E=0.1%, then 0.025% of voltage flatness is required.
- Water cooling variation of tube body also causes rf phase variation.

This happens since water temeperature changes the gain cavitiy's detuning frequency and bunch center changes from original position.

this phase variation is roughly

0.5-1 deg.phase/1 deg water temp.



Applied Voltage and power-gain relationship

Applied voltage and input power vs output power



Generally higher the applied voltage, lower the saturated point is and Higher the gain is.

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Electron gun and beam generation

Structure of electron gun in the klystron

From the requirement of large current, electrons generated from the large aperture cathode are focused and emitted to the drift tube.

Cathode: 900-1100 deg. Thermal electrons are emitted

Beam forming electrode (BFE)

form the laminar flow

beam.

Anode: entrance to drift tube

Generally cathode is negative and anode is o volt.



Temperature limited (TL) flow and space-charge (SC) limited flow

As cathode surface temperature getting higher due to the heater power up, thermal electrons are start to emit from the cathode surface.

• Current is described by the Richardson-Dushman's formula.

$$J = A_0 T^2 e^{-\frac{\varphi}{kT}}$$

- T is absolute temperature, φ is work function of the cathode and k is the Boltzmann constant. This current emission range is called as temperature limited region(TL).
- More higher the cathode temperature is, cathode surface is filled with space charge and current does not increase as temperature is getting high.
- Emission of this range is called space charge limited region (SC).
- Emitted current is determined by the geometry of the gun and applied voltage.
- Current is proportional to power of 3/2 of the voltage. Ideal SC flow is called as FSCL: Full Space Charge Limit. Real cathode deviates slightly from FSCL.
- FSCL Emission from the parelle $\frac{1}{9} = \frac{1}{2} \frac$

TL flow and SC flow



Accelerators of electron and ion

Heater adjustment and the klystron life

- Usually operation point is the saturated point because the current fluctuation is minimum for other parameter's fluctuation
- Heater power setting point is important because it affects the stabilities and klystron life. From Miram plot, following way is recommended.



- Measuring 1 point on the Miram plot takes about 30 min. to reach to the stable current.
- After the long usage, due to the degradiation of thecathode, emission decrease gradually and you must readjust the operating point.

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Convenient method to measure Miram plot DIP testing

Usually it takes a long time to complete the measurement of Miram plot because at each point you must wait for the heat equilibrium. Half day per one klystron is required, and the institute having many klystrons has a difficult to have a measurement frequently.

Dip testing is a convenient way to evaluate the operation point of the cathode.

During the operation, quick heater off is done and the dip (decreasing amount of current) is measured.

Special care is for abnormal HV in Line type modulator. Interlock off sequence is needed.





Multi-beam klystron for ILC



10MW 1.5ms 67% efficiency

Scope picture of the klystron test. The lines show the klystron voltage (116 kV) in yellow, the current (128 A) in blue and RF output (5 MW each) in magenta and green.



Technology for MBK

Microwave is amplified by the klystron. In klystron, microwave cavity is used to modulate the beam velocity by small power. Modulated beam reach to its maximum bunching at the output cavity, and generate high power microwave.

magnetic field is curing-

6 electron beams from 6 thermionic cathode

output waveguide for high power micro-wav

-microwave cavity to make beam velocity modulation

coils for beam focusing

Important parameter; Perveance

Accelerator Laboratory, KEK

Definition of Perveance



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Low perveance klystron has high efficiency but applied voltage is high.

Modulator

Requirement to RF source from accelerator specification

- Energy Gain E
 - It depends on the accelerator final energy, and it is the SQRT of P (proportional to electric field)
- Energy width $\delta E/E$ should be as small as possible
 - » this corresponds to minimize $\Delta P/P$ and $\Delta \theta/\theta$.
- In order to achieve these requirements, good quality of modulator (good stability of output pulse) is required.

Various Modulator

- Modulator for short pulse (~ microsecond order) electron linac
 - Line type modulator: most popular, low cost, simple
 - Pulse forming
 - » PFN (pulse forming network)
 - » Blum Line
 - Hard tube pulser (Solid state amplifier)
 - Pulse amplifier
 - Pulse generation by IGBT
 - Magnetic compressor modulator
 - Marx Generator
- Modulator for long pulse(~ a few hundred microseconds to a few milliseconds) proton linac
 - IGBT modulator with bouncer circuits
 - Marx generator

Modulator(1) Line-type Modulator

Principle of Line Type Modulator (Most popular modulator)



• Pulse width is determined by the traveling time of the line

$$\tau = \frac{2\ell}{u}$$
....where ℓ is the length of line

• Matching condition (Z0 is characteristic impedance of co-axial line) $Z_0 = R_c$
Line-type Pulser







Discharging Circuit





• Analysis of N stage pulse forming network (PFN) 1st stage $L \frac{di_1(t)}{dt} + R_i i_1(t) + \frac{1}{C} \int_0^t (i_1(\tau) - i_2(\tau)) d\tau = E$

r-th stage

$$L\frac{di_{r}(t)}{dt} + \frac{1}{C}\int_{0}^{t}(i_{r}(\tau) - i_{r-1}(\tau))d\tau + \frac{1}{C}\int_{0}^{t}(i_{r}(\tau) - i_{r+1}(\tau))d\tau = 0$$

n-th stage

$$L\frac{di_{n}(t)}{dt} + \frac{1}{C}\int_{0}^{t}(i_{n}(\tau) - i_{n-1}(\tau))d\tau + \frac{1}{C}\int_{0}^{t}i_{n}(\tau)d\tau = 0$$



Solving this exactly is difficult and using Laplace transformation with suitable approximation or computer simulation is frequently used.

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Characteristics of PFN

 For n-stage PFN pulse width

$$\tau = 2\sqrt{L_{\rm N}C_{\rm N}} \approx 2n\sqrt{LC}$$

where
$$L_N = \sum L_i = nL$$
, $C_N = \sum C_i = nC$

Characteristic impedance of PFN $Z_{PFN} = \sqrt{\frac{L_N}{C_N}} = \sqrt{\frac{L}{C}}$

Requirement of PFN-Parameter

- Klystron's operation point V_s , I_s then $Z_s = V_s / I_s$
- Step up ratio of pulse transformer n, then primary impedance is $Z_s = Z_s / n^2$
- From matching condition, PFN characteristic impedance $Z_{PFN} = Z_S$
- Pulse width τ is come from Klystron's requirement or system design.
- Total capacitance of PFN is derived by energy equation: energy stored in PFN=energy supplied to the load

$$\frac{1}{2}C_T V_C^2 = \int_0^\tau V_p I_p dt$$
or
$$C_T = \frac{2V_p I_p \tau}{V_C^2}$$

• stage number is determined by flat top condition

PFN Simulation Example



L=1.3[µH] L2=0[H] C=0.015[µF] Stage number of PFN 1,3,5,10,20



Operation Statistics in FY2007

Linac failure distribution



Reliability of an RF system is directly linked to the linac availability.

Modulator availability=0.997

•Air cooling fan

Modulator failure distribution

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S. Fukuda: Indo-Japan school on Advanced Accelerators of electron

and ion

Status of Thyratron

• 45 kV, 5 kA, 6 µs, 50 Hz Switching



Litton EEV ITT L4888B CX2410K F-241

Thyratron circuit



Anode

Driver circuit •Keep alive has ~250 mA dc current at 100 V

• Lifetime Profile



Matching and mismatching

• For lossless transmission line, current transformation is

$$i(p) = \frac{V_g}{p(R_\ell + Z_0 \operatorname{coth} p\delta)} = \frac{V_g}{p(Z_0 + R_\ell)} \cdot \frac{1 - e^{-2p\delta}}{1 + \frac{Z_0 - R_\ell}{Z_0 + R_\ell}} e^{-2p\delta}$$
$$= \frac{V_g (1 - e^{-2p\delta})}{p(Z_0 + R_\ell)} \left[1 - \frac{Z_0 - R_\ell}{Z_0 + R_\ell} e^{-2p\delta} + (\frac{Z_0 - R_\ell}{Z_0 + R_\ell})^2 e^{-4p\delta} \dots \right]$$

• And its inverse transformation,

$$i(t) = \frac{V_0}{Z_0 + R_\ell} \left\{ 1 - U(t - 2\delta) - \frac{Z_0 - R_\ell}{Z_0 + R_\ell} \left[U(t - 2\delta) - U(t - 4\delta) \right] - \frac{Z_0 - R_\ell}{Z_0 + R_\ell} \left[U(t - 2\delta) - U(t - 4\delta) \right] + \left(\frac{Z_0 - R_\ell}{Z_0 + R_\ell}\right)^2 \left[U(t - 4\delta) - U(t - 6\delta) \right] + \cdots \right\}$$
where $U(\Delta t) = 1$ for $\Delta t > 0$ and $U(\Delta t) = 0$ for $\Delta t < 0$
 $\Delta t = (t - n\delta), \quad n = 2, 4, 6 \cdots$

- Therefore, depending on R_{ℓ} , waveform is different after t=2 δ .
- $R_{\ell} = Z_0$ matching condition and no reflection
- $R_{\ell} > Z_0$ mismatch (positive mismatch) extreme case :open end lower operation point than normal
- *R_l* < *Z*₀ mismatch (negative mismatch) extreme case :short end



Protection Circuit for load discharge etc.

 If discharge occurred in klystron or pulse transformer circuit, pulse reflection occurs due to the mismatching effects. Serious case, undesirable inverse voltage causes the failure of various devices. Therefore, protection circuit is employed in the system and it force to stop operation with a pulse or a few pulses later.

THYRATON

TRANSFORMER



• Fast protection: End of line clipper (within a pulse response)



Fig. 17. The pulse voltage (upper, peak 12 kV) and the EOI clipper current (lower, peak 300 A). Load 3.5 Ω , 2 μ s/div.

• Rather slow protection: reversed shunt circuit

DISTRIBUTED

CAPACITANCE

Average of inversed current due to the load discharge is sensed and stop operation by meter relay etc.



Commercial Solid-state Amplifier (Scandinova)



Parameters	K2-3	Unit
RF Peak Power	30- 60	[MW]
Pulse Voltage	280 - 450	[kV]
Pulse Current	230 - 450	[A]
Modulator Peak Power	160	[MW]
Modulator Average Power	0,5 - 100	[kW]
Mains: 1-phase / 3-phase	3	
Cooling	Water	

RF POWER UP TO 60 MW MODULATOR PEAK POWER UP TO 160 MW

Pulse transformer is used to step up the voltage

IUAC is planning to introduce this type of modulator.

Modulator other than Line-Type

Pulse Modulator Using Multi-Series Switch(1)

• Series Switch Modularor

• Marx Type Modulator





Flexible
 Active waveform control
 Pulse waveform
 Pulse flatness

Series Switch Modulator (Diversified Technologies, Inc.)





Figure 2. 140kV, 500A solid-state switch

IGBT Series Switch

140kV, 500A switch shown at left in use at CPI

As a Phase II SBIR, DTI is building a 120 kV, 130 A version with a bouncer to be delivered to SLAC at the end of 2006



Figure 3: Test pulse (140 kV, 160 A, 13 µsec) of solid-state modulator. Upper trace is voltage at 63 kV/division. Lower trace is current at 100 A/division

Other Alternative Modulators

SNS High Voltage Converter Modulator (Unit installed at SLAC)



RECTIFIER TRANSFORMER AND FILTERS

SCR REGULATOR

HVCM

EQUIPMENT CONTROL RACK

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Longer Pulse Modulator with sag compensation with RC circuit



Long Pulse Modulator with Bouncer Circuit(2)





Actual Waveform by Bouncer Circuit

Accelerator Laboratory

•With Bouncer Circuit



Es=20kV, Pw=1.7ms, fr=5pps Rise-time(10-90%)=33µs

Es=17kV, Pw=1.7ms, fr=5pps Flatness=0.8%(p-p)

Protection of Klystron at Breakdown



LS-9.0 KV, FW-1.7 IIIS, II-

Pulse Transformer Modulator Status

IGCT Stack

- 10 units have been built, 3 by FNAL and 7 by industry (PPT with components from ABB, FUG, Poynting).
- 8 modulators are in operation.
- 10 years operation experience.
- Working towards a more cost efficient and compact design.
- FNAL building two more, one each for ILC and HINS programs – SLAC has bulit switching circuits.



HVPS and Pulse Forming Unit



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Marx Modulator for ILC

Marx Generator Modulator





12 kV Marx Cell (1 of 16)

- IGBT switched
- No magnetic core
- Air cooled (no oil)

SLAC's New Type Marx Modulator : P2

P2 Nearly Assembled







Parameters

Parameter	Value	Note
AC to DC bus efficiency	~85%	Commercial power supply
DC bus to pulse output efficiency	>95%	Calculated
Modulator flattop	+/-0.2%	Achieved, 17/32 cells
	+/-0.1%	Anticipated
Voltage output repeatability	<+/-0.1%	Anticipated

Vendor Design Marx Modulator for ILC





Thomson Marx Modulator: Low voltage Marx and Pulse Transformers ASSEMBLY Full Voltage/Current/PW Spec



- Modulator tank footprint ~1.5m x 2.5m
 Height ~ 2 m including controls
 (doghouse)
- Local controls in front panel and remote in the rear panel.





Voltage:	120kV
Current:	130A
Pulse width:	1.5ms



- Modulator has demonstrated full spec single pulsing into a resistive load.
- Due to source and load limitations, full spec pulsing has been demonstrated at 5Hz with a double full PW pulse, three 1ms pulses and ten 150 us pulses.

DTI's Marx Modulator: 120kV Direct Pulse Generation

Marx Modulator's Feature

 Good flat top pulse when pulse duration is long such as a few millisecond.

(timing adjustment of individual Marx cell enable to make a good flat top)

- Even a direct output pulse case, acring probability in the modulater is small due to comprise of the low voltage cell's assembly
- Fast shutoff of the output when klystron fails.

Power Distribution System (Waveguide System)

Layout of RF System in KEK

RF System Diagram C-band Plan(example)



Importance of Power Distribution System

- Cost of RF system is expensive, and about 1/3 of cost is PDS cost.
- Sometimes RF efficiency and capability are determined by PDS. For example, SLED (energy doubler) specifies the peak power capability.
- Fractions of the failures of linac are come from poor design of PDS.
- PDS variants
 - Coaxial waveguide PDS: low peak power, low frequency
 - Rectangular waveguide PDS of air, nitrogen and SF6 w/o pressurizing.
 - Rectangular waveguide PDS in vacuum
 - PDS with circulator for cw/longer pulse operation, feeding to standing wave cavity structure
 - Vacuum window or waveguide valve to keep structure low pressure when klystron is replaced.
 - Power divider system w/o changing the delivering power
 - Phase shifter system or fixed length of waveguide considering the phase at cavity and beam

Layout of Waveguide in Electron Linac



Exact phase adjustment between the acc. structures is required.

For the phasing of prebuncher, buncher, Phase shifter and variable power dividers are required. For easy manufacturing, pressurizing system is employed.

Waveguide phase-shifters are eliminated because of saving the money.

Example of waveguide system in ILC Local PDS Layout of KCS / DKS



2015/02/1/

LLRF (Low Level RF)

Low level RF System



System includes master oscillator(MO), local oscillator(LO), timing module, down converter and digital RF controller. Pulse modulator and driver amplifier Is also included. RF protection system including slow starter of RF is in this area.

Function of LLRF

- Low level RF system is the system from master oscillator to the input rf for main klystron.
- Stable rf (frequency, power and phase) is required.
- Beam loading compensation is sometimes requested.
- Most important function of LLRF for the accelerator is a stable phase. Phasing is also important when the electron energy is changed.
- Feed forward/feed back for the output power and phase is required. Recently digital feed back is becoming more popular.

Feed forward or feed back control

- Upper System
 - Its output does not change the input signal (Feed forward control)
- Lower System
 - Parts of output signal goes back to the input signal and input is changed.
 (Closed loop control or Feedback control)
 - Digital Feedback

ADC changes digital signal and then digitally controlled. Delay time is inevitable. Usually expensive. Easy to change.

Analogue Feedback

No delay. Not easy to change. Inexpensive.



PID Control

- PID Control is one of popular control method.
- P=proportional, I=Integral, D=derivative



- P-control feedbacks the deviation to control signal U(s), and current information is reflected.
- I-control feedbacks the integration of the deviation to U(s) and past information is reflected.
- D-control feedbacks the derivative of the deviation to U(s) and future information is reflected.

Digital RF Controller

Digital controller comprises of ADC, DAC and DSP/FPGA.

DSP (Digital Signal Processor):

This has a signal processor in the device and its calculation ability is powerful.

Between ADC/DAC and DSP, there required the buffer device and buffer device is not synchronized with sampling signal.

A few microsecond delay time is inevitable.

FPGA(Field Programmable Gate Array):

Algorism of signal process is generated of numerical formula written by the hardware language. Synchronized operation with the clock signal of ADC/DAC and FPGA. Faster than DSP.

Recently FPGA is becoming more popular.



Amplitude-phase and IQ control

Important parameter in RF is signal's amplitude and phase. Signal from cavity is also amplitude and phase, and this means the measurement of Icomponent and Q-component of RF signal



IQ and polar coordinate Relationship



Amplitude and phase measurement



IQ measurement

Using the sampling signal of IF (Intermediate Frequency), direct I and Q signals are possible to be Measured.


Example of LLRF in KEK STF



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Example of LLRF in KEK cERL



Thanks for listening my lecture